

Features

- High Thermal Efficiency
- Complete Power Control Circuits in a Single Package

DESCRIPTION

These modules provide complete power control in a single package, utilizing high thermal efficiency to assure long life and reliable performance. Six standard models provide 2500 Vrms isolation from all terminals to ceramic base and are UL recognition pending.

PART NUMBER IDENTIFICATION EX.: CSD250/16

 Series Type
 Current
 Voltage

 CSD-Case style
 62 - 60 Amps
 06 - 600

 82 - 80 Amps
 08 - 800

 160 - 180 Amps
 10 - 1000

 210 - 200 Amps
 12 - 1200

 250 - 25 0 Amps
 14 - 1400

 16 - 1600

ELEC	TRICAL SPECIFICATION	160	210	250	
SYMBO	L SPECIFICATION		RATINGS		
ID	Maximum DC Output Current (Tc = 85°C)	180 Amps	200 Amps	250 Amps	
V _F	Maximum Voltage Drop @ Amps Peak	1.65V @ IF=300A	1.43V @ IF=300A	1.43V @ IF=300A	
T _J	Operating Junction Temperature Range	-40°C to +125°C			
di/dt	Critical Rate of Rise of On-State Current @ TJ=125°C	100A/µs	100A/µs	100A/µs	
dv/dt	Critical Rate of Rise of Off-State Voltage [V/µs]	1000V/µs	1000V/μs	1000V/μs	
V _{RRM}	Repetitive Peak Reverse Voltage (AC Line)	400 (120 Vac) 600 (240 Vac) 1000 (380 Vac) 1200 (480 Vac) 1400 (530 Vac) 1600 (600 Vac)			
I _{TSM}	Maximum Non-Repetitive Surge Current $\binom{1}{2}$ Cycle, 60Hz)	1800A	2200A	2750A	
I ² T	Maximum I ² T for Fusing (t=8.3ms) [A ² sec]	16200	36000	45000	
R _{qJC}	Maximum Thermal Resistance Junction to Ceramic Base per Chip	0.65°K/W	0.45°K/W	0.45°K/W	
V _{ISOL}	Isolation Voltage	2500 V _{RMS}	2500 V _{RMS}	2500 V _{RMS}	

MECHANICAL SPECIFICATIONS

Weight: (typical) 9.5 oz. (270g)

©C3 Semiconductors, LLC. All rights are reserved

For recommended applications and more information contact: USA: Sales Support (888) 882-8689

Email: sales@c3semi.com WEB SITE: http://www.C3semi.com



Features

- High Thermal Efficiency
- Complete Power Control Circuits in a Single Package

DESCRIPTION

These modules provide complete power control in a single package, utilizing high thermal efficiency to assure long life and reliable performance. Six standard models provide 2500 Vrms isolation from all terminals to ceramic base and are UL recognition pending.

PART NUMBER IDENTIFICATION

Series Type CSD-Case style Current 62 - 60 Amps 82 - 80 Amps 160 - 180 Amps 210 - 200 Amps 250 - 250 Amps

EX.: CSD250/16

Circuit Type Voltage (see schematic diagram) 08 - 800

Three Phase Bridge 10 - 1000 12 - 1200 14 - 1400 16 - 1600

ELECT	RICAL SPECIFICATION	62	82	
SYMBO	L SPECIFICATION	RA	RATINGS	
ID	Maximum DC Output Current (Tc = 85°C)	60 Amps	80 Amps	
V _F	Maximum Voltage Drop @ Amps Peak	1.8V @ IF=150	1.6V @ IF=150A	
	Operating Junction Temperature Range	-40°C to +	125℃	
di/dt	Critical Rate of Rise of On-State Current @ TJ=125°C	100A/μs	100A/μs	
dv/dt	Critical Rate of Rise of Off-State Voltage [V/µs]	1000V/μs	1000V/μs	
V_{RRM}	Repetitive Peak Reverse Voltage (AC Line)	400 (120 Vac) 600 (240 Vac) 1000 (380 Vac) 1200 (480 Vac) 1400 (530 Vac) 1600 (600 Vac)		
I _{TSM}	Maximum Non-Repetitive Surge Current $\binom{1}{2}$ Cycle, 60Hz)	550 A	740 A	
I ² T	Maximum I ² T for Fusing (t=8.3ms) [A ² sec]	1520	2800	
R_{qJC}	Maximum Thermal Resistance Junction to Ceramic Base per Chip	1.45°K/W	1.1°K/W	
V _{ISOL}	Isolation Voltage	2500 V _{RMS}	2500 V _{RMS}	

MECHANICAL SPECIFICATIONS

Weight: (typical)

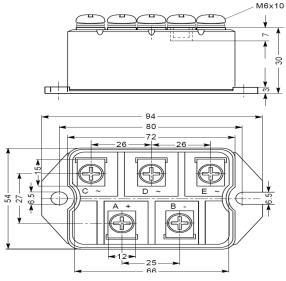
5.64 oz. (160g)

© C3 Semiconductors, LLC. All rights are reserved

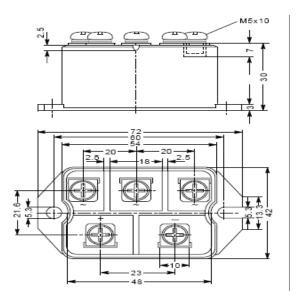
For recommended applications and more information contact: USA: Sales Support (888) 882-8689

Email: sales@c3semi.com WEB SITE: http://www.C3semi.com

MECHANICAL DIMENSIONS AND CIRCUIT DIAGRAM

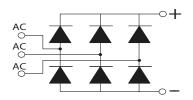


Package Dimensions for 180-250 Amp Models



Package Dimensions for 60 and 80 Amp Models

SERIES CSD CIRCUIT



 $^{\hbox{$\odot$}}\text{C3}$ Semiconductors, LLC. All rights are reserved

For recommended applications and more information contact: USA: Sales Support (888) 882-8689

Email: sales@c3semi.com WEB SITE: http://www.C3semi.com